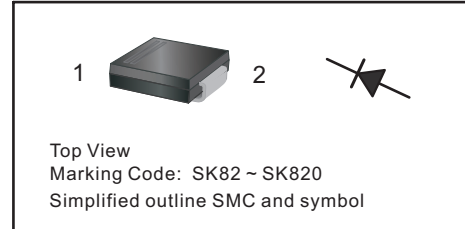


Surface Mount Schottky Barrier Rectifier  
 Reverse Voltage - 20 to 200V Forward Current - 8.0A

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



### FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

### MECHANICAL DATA

- Case: SMC
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.22g / 0.0077oz

### Absolute Maximum Ratings and Electrical characteristics

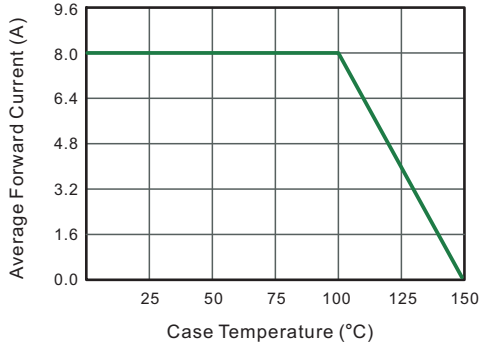
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SK82CG	SK84CG	SK86CG	SK88CG	SK810CG	SK812CG	SK815CG	SK820CG	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	$V_{RMS}$	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	8.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	150								A
Max Instantaneous Forward Voltage at 8 A	$V_F$	0.45	0.55	0.70		0.85			V	
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$	$I_R$	1.0 50								mA
Typical Junction Capacitance <sup>(1)</sup>	$C_j$	600		400						pF
Typical Thermal Resistance <sup>(2)</sup>	$R_{\theta JA}$	35								°C/W
Operating Junction Temperature Range	$T_j$	-55 ~ +150								°C
Storage Temperature Range	$T_{stg}$	-55 ~ +150								°C

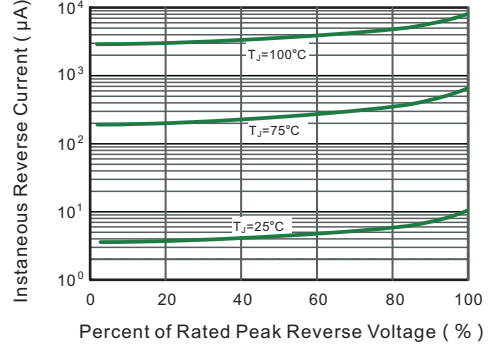
(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

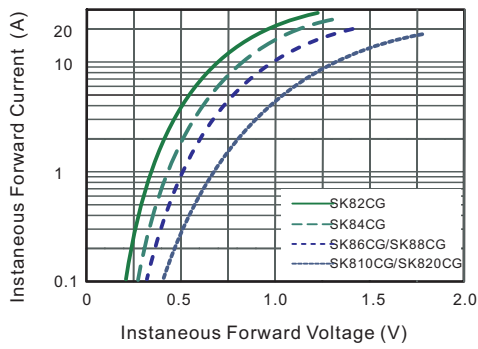
**Fig.1 Forward Current Derating Curve**



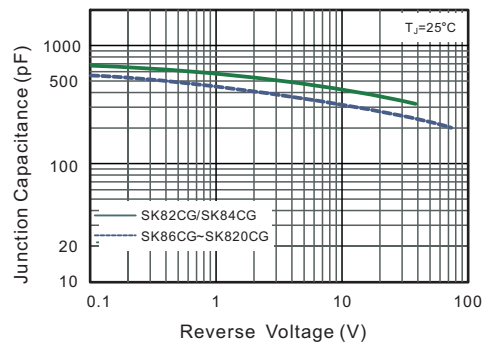
**Fig.2 Typical Reverse Characteristics**



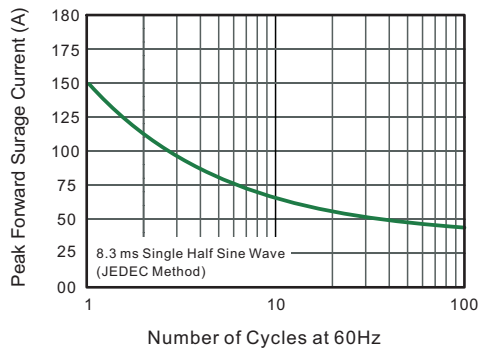
**Fig.3 Typical Forward Characteristic**



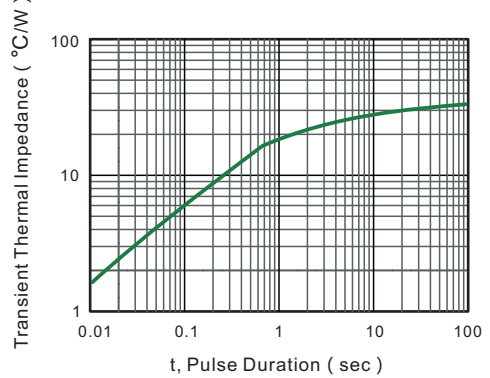
**Fig.4 Typical Junction Capacitance**



**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



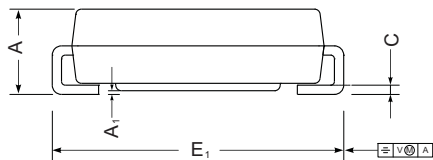
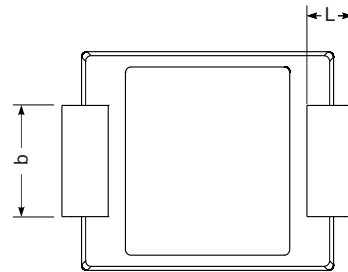
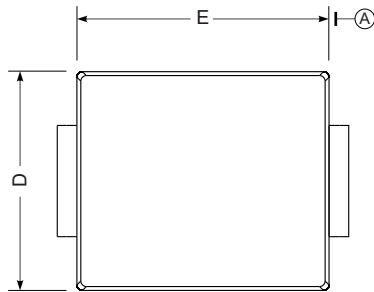
**Fig.6- Typical Transient Thermal Impedance**



## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

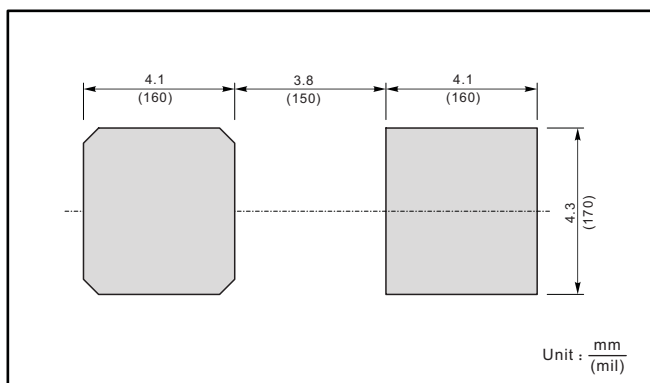
SMC



SMC mechanical data

UNIT		A	E	D	E <sub>1</sub>	A <sub>1</sub>	C	L	b
mm	max	2.62	7.0	6.2	8.0	0.21	0.31	1.6	3.25
	min	2.00	6.5	5.6	7.6	0.05	0.15	0.9	2.75
mil	max	103	276	244	315	8.3	12	63	128
	min	79	256	220	299	2.0	5.9	35	108

### The recommended mounting pad size



### Marking

Type number	Marking code
SK82CG	SK82
SK84CG	SK84
SK86CG	SK86
SK88CG	SK88
SK810CG	SK810
SK812CG	SK812
SK815CG	SK815
SK820CG	SK820

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